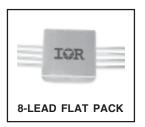


Ultra Low Dropout Linear Regulator

OMR9601SF +3.3Vin to +2.5Vout at 3.0A

Product Summary

Part Number	Dropout	I _O	V _{in}	V _{out}
OMR9601SF	0.4V	3.0A	3.3V	2.5V



The OMR9601SF is a space qualified, ultra low dropout linear regulator designed specifically for space applications. This product has been characterized to a total ionizing dose of 1.0 Mrad (Si) per MIL-STD-883, Method 1019, Condition D at both high and low dose rates under biased and unbiased conditions to account for ELDRS effects in bipolar devices. The ultra low dropout voltage of 0.4V @ 3A makes the part particularly useful for applications requiring low noise and higher efficiency.

Features:

- Total dose to 1.0 Mrad (Si) and low dose capability to 500 krad (Si) allows use in space applications
- Single Event latchup Immune LET= 84 MeV/(mg/cm²) Fluency = 1x10° ions/cm²
- Low noise, higher efficiency
- Ultra low dropout voltage of 0.4V@ 3A out significantly reduces power consumption
- Remote shutdown permits power sequencing to be easily implemented
- Hermetic 8-lead flat pack ensures higher reliability
- K-level screened
- This part is also available in MO-078 Package as OMR9601SC

Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Output Current	Io	3.5	Α
Input Voltage	V _{in}	7	V
Power Dissipation T _C = 25°C	P _{TOT}	19	W
Thermal Resistance, Junction to Case	R _{THJC}	6.5	°C/W
Operating Temperature Range	T _J	-55 to +125	
Storage Temperature Range	T _S	-65 to +150	°C
Lead Temperature	T _L	300	

Electrical Characteristics @Ta = 25°C (Unless Otherwise Specified) Pre-Radiation

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	$V_{in} = 3.3V, I_O = 1.5A$		2.475	2.5	2.525	
	$V_{in} = 3.135V, I_{O} = 50mA$		2.375	-	2.625	
Output Voltage	$V_{in} = 3.135V, I_O = 3.0A$	V _{out}	2.375	ı	2.625	V
	$V_{in} = 3.465V, I_{O} = 50mA$		2.375	ı	2.625	V
	$V_{in} = 3.465V, I_O = 3.0A$		2.375	ı	2.625	
Input Voltage Range - Operating	$I_{O} = 3.0A$	V_{in}	2.9	-	6.5	
Dropout Voltage	$I_0 = 3.0A, V_{out} = 2.5V$	V_{drop}		-	0.4	
Current Limit	V _{in} = 3.3V, Overcurrent Latch Up	I _{latch}	3.0	-	-	Α
Ripple Rejection	F = 120Hz, I _{out} = 50mA		65	-	-	dB
Shutdown Source Current	$V_{shdn} = 5.0V$	l _{shdn}	-	200	-	μΑ
Shutdown Pin Threshold ^①	$V_{in} = 3.3V$	$V_{\sf shdn}$	1.0	-	1.6	V
Output Voltage at Shutdown	$V_{in} = 3.3V, I_{O} = 50mA, Vshdn = +5.0V$	Vout (shdn)	-0.1	ı	+0.1	V

Electrical Characteristics @Ta = -55°C to 125°C (Unless Otherwise Specified) Pre-Radiation

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	$V_{in} = 3.3V, I_O = 1.5A$		2.375	2.5	2.625	
	V _{in} = 3.135V, I _O = 50mA		2.375	-	2.625	
Output Voltage	V _{in} = 3.135V, I _O = 3.0A	V _{out}	2.375	-	2.625	v
	$V_{in} = 3.465V, I_{O} = 50mA$		2.375	-	2.625	ľ
	$V_{in} = 3.465V, I_O = 3.0A$		2.375	ı	2.625	
Input Voltage Range - Operating	$I_{O} = 3.0A$	V _{in}	2.9	-	6.5	
Dropout Voltage	$I_0 = 3.0A, V_{out} = 2.5V$	V_{drop}	-	-	0.4	
Current Limit	V _{in} = 3.3V, Overcurrent Latch Up	I _{latch}	3.0	-	-	Α
Ripple Rejection	F = 120Hz, I _{out} = 50mA		65	-	-	dB
Shutdown Source Current	$V_{shdn} = 5.0V$	l _{shdn}	-	200	-	μΑ
Shutdown Pin Threshold①	$V_{in} = 3.3V$	V_{shdn}	1.0	-	1.6	V
Output Voltage at Shutdown	$V_{in} = 3.3V$, $I_{O} = 50mA$, $V_{Shdn} = +5.0V$	V _{out (shdn)}	-0.1	-	+0.1]



Electrical Characteristics $@T_a = 25^{\circ}C$ (Unless Otherwise Specified) Post-Radiation

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	$V_{in} = 3.3V, I_O = 1.5A$		2.375	-	2.625	
	$V_{in} = 3.135V, I_{O} = 50mA$		2.375	-	2.625	
Output Voltage	$V_{in} = 3.135V, I_{O} = 3.0A$	V_{out}	2.375	-	2.625	V
	$V_{in} = 3.465V, I_{O} = 50mA$		2.375	-	2.625	
	$V_{in} = 3.465V, I_{O} = 3.0A$		2.375	-	2.625	
Current Limit	$V_{in} = 3.3V$	I _{max}	3.0	-	-	Α
Ripple Rejection	F = 120Hz, I _{out} = 50mA		40	-	-	dB
Output Voltage at Shutdown	$V_{in} = 3.3V$, $I_{O} = 50$ mA, V shdn = +5.0 V	V _{out (shdn)}	-0.1	-	+0.1	V

Notes for Electrical Characteristic Tables

 \odot V_{Shutdown} ramp from 0.8V to 4.8V, output monitored for a 100mV drop below the nominal specification for V_{out}

Pre-Radiation Characteristics

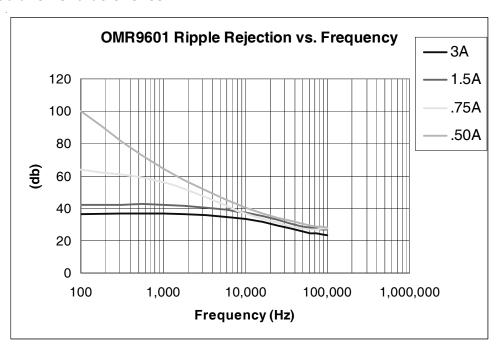


Fig 1. Ripple Rejection Vs Frequency

OMR9601SF

International Rectifier

Post-Radiation Characteristics Total Ionizing Dose (TID)

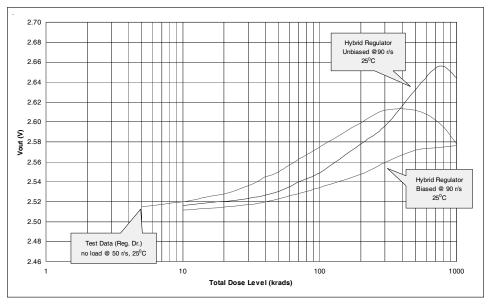


Fig 2. Voltage Output Vs Total Ionizing Dose

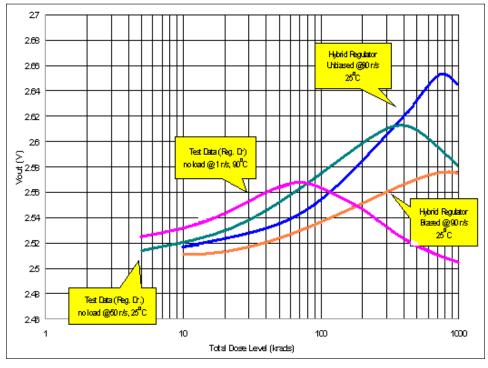


Fig 3. Voltage Output Vs Total Ionizing Dose

OMR9601SF

International

TOR Rectifier

Post-Radiation Characteristics

Enhanced Low Dose Rate Sensitivity (Dose Rate = 0.1 Rad/s)

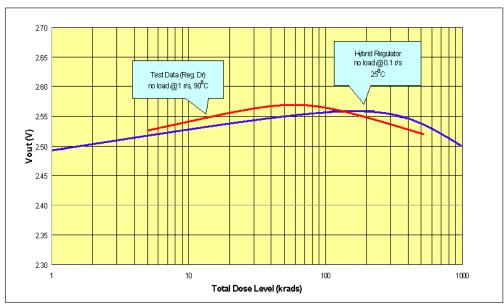


Fig 4. Voltage Output Vs Total Ionizing Dose

Single Event Latch-up

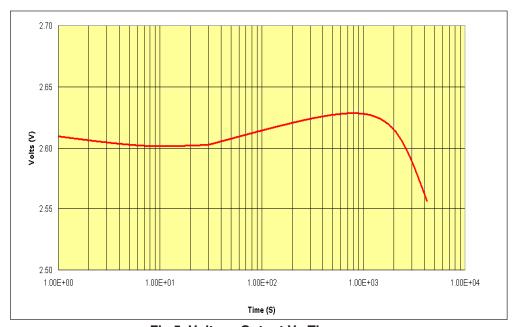


Fig 5. Voltage Output Vs Time

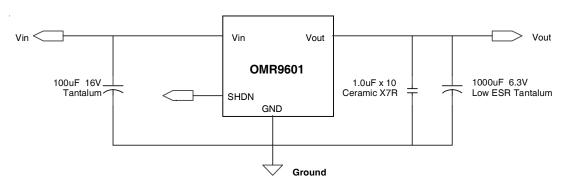


Fig 6. Typical Application Circuit

Input Capacitance

Recommended input capacitance for a generic application is a $100\mu F$, 16V tantalum capacitor. However, the input capacitance is not critical to the stability of the regulator and is therefore application dependent. In designs with a clean bus voltage that is situated close to the input of the regulator, only a small ceramic capacitor will be needed to decouple high frequency noise. On the other hand, in designs with a noisy bus, a larger capacitor will be needed. Care should be taken to ensure that the input to the regulator is sufficiently free of noise and disturbances.

Output Capacitance

Like most ultra low dropout voltage regulators, OMR9601 requires the use of an output capacitor as part of the device frequency compensation. The device requires a minimum of 220µF tantalum to ensure stability.

Many different types of capacitor are available and have widely varying characteristics. These capacitors differ in capacitor tolerance, equivalent series resistance (ESR), equivalent series inductance and capacitance temperature coefficient. The OMR9601 frequency compensation optimizes frequency response with low ESR capacitors. In general, use capacitors with an ESR of less than 50 m Ω for heavy load applications.

High quality bypass capacitors must also be used to limit the high frequency noise generated by the load. Multiple small ceramic capacitors are typically required to limit parasitic inductance (ESL) and ESR in the capacitors to acceptable levels.

The upper limit of the capacitance is governed by the delayed over-current latch function of the regulator. The regulator has a protection circuit that will latch the device off in the event of a short circuit. However, since it is known that the regulator will draw a large in-rush current upon startup, the latch-off is delayed by about 10ms to allow the output capacitors to charge to a steady state without shutting down. During this period, the regulator will have an output current at its maximum of around 5A typical. Therefore, the maximum output capacitance can be as high as 20,000uF without causing device to latch-off during start-up.

Figure 6 shows a typical application circuit. The output load capacitor consists of one tantalum capacitor (or more in parallel) of $1,000\mu F$ with ESR no high than $50~m\Omega$, and $10~x~1.0\mu F$ X7R ceramic caps. This will give approximately 59 degrees phase and 24dB gain margin.



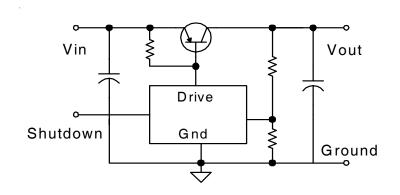


Fig 7. Simplified Schematic Circuit

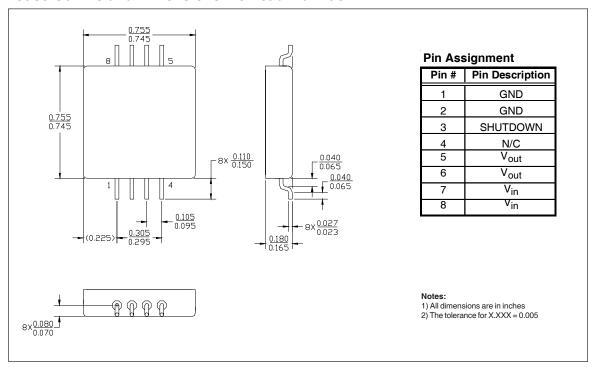
MIL-PRF-38534 Screening Requirements

TEST/INSPECTION	SCREENING LEVEL	MIL-STD-883	
	CLASS K (Space Level)	METHOD	
Pre Seal Burn-In	Optional	1030	
Nondestructive Bond Pull	100%	2023	
Internal Visual	100%	2017	
Temperature Cycle	100%	1010	
Constant Acceleration	100%	2001	
Mechanical Shock	100%	2002	
PIND	100%	2020	
Pre Burn-In-Electrical	100%		
Burn-In	100%	1015	
Final Electrical	100%		
Seal	100%	1014	
Radiographic	100%	2012	
External Visual	100%	2009	

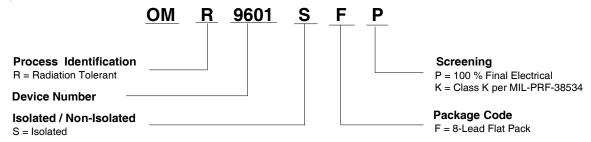
Note:

International Rectifier does not currently have a DSCC certified Radiation Hardness Assurance Program

Case Outline and Dimensions - 8-Lead Flat Pack



Part Numbering Nomenclature



International Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
IR LEOMINSTER: 205 Crawford St., Leominster, Massachusetts 01453, USA Tel: (978) 534-5776

TAC Fax: (310) 252-7903

Visit us at www.irf.com for sales contact information.

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